

## SAM™ Data Sheet SAM-1064-60-4ps-x, λ = 1040 nm

| Laser wavelength  | $\lambda = 1064 \text{ nm}$                               |
|---|---|
| High reflection band  | λ = 1010 1110 nm  |
| Absorbance  | A <sub>0</sub> = 60 %                                     |
| Modulation depth  | ∆R = 36 %   |
| Non-saturable loss  | A <sub>ns</sub> = 24 %                                    |
| Saturation fluence  | $\Phi_{sat}$ = 30 µJ/cm <sup>2</sup>                      |
| Relaxation time constant  | τ ~ 4 ps  |
| Damage threshold  | $\Phi$ = 600 µJ/cm <sup>2</sup>                           |
| Chip area   | 4.0 mm x 4.0 mm; other dimensions on request              |
| Chip thickness  | 450 μm  |
| Protection  | the SAM is protected with a dielectric front layer        |
| Mounting option x denotes the type of mounting as follows:<br>x = 0 unmounted<br>x = 12.7 m where a need related Cu culinder with 12.7 mm C |   |
| <b>x</b> = 12.7 g   | glued on a gold plated Cu-cylinder with 12.7 mm $\oslash$ |

x = 12.7 gglued on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$ x = 25.4 gglued on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ x = 12.7 ssoldered on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$ x = 25.4 ssoldered on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ x = FCmounted on a 1 m monomode fiber cable with FC connector

## Low intensity spectral reflectance

